## NSN 5961-01-250-1587

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-250-1587 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1400.0 collector-to-emitter, with voltage between base and emitter and 800.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 250.00 microamperes repetitive peak forward current preset **Power Rating Per Characteristic:** 175.0 watts large-signal input power, common-emitter absolute **Transfer Ratio:** 7.5 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life:

Demilitarization:

**Unit Of Measure:** 

No

N/a

## **NSN 5961-01-250-1587** Transistor - Page 2 of 2



Fiig:

A110a0